Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.34$ V at $I_F = 2.5$ A



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DESIGN SUPPORT TOOLS



| PRIMARY CHARACTERISTICS | | | | |
|-------------------------|-------------------------------|--|--|--|
| I _{F(AV)} | 2 x 5.0 A | | | |
| V _{RRM} | 45 V | | | |
| I _{FSM} | 100 A | | | |
| V_F at $I_F = 5.0$ A | 0.41 V | | | |
| T _J max. | 150 °C | | | |
| Package | D ² PAK (TO-263AB) | | | |
| Circuit configuration | Common cathode | | | |

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum FREE peak of 245 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | |
|------------------------------------------------------------------------------------|------------|------------------|-------------|------|--|--|
| PARAMETER | | SYMBOL | VBT1045C | UNIT | | |
| Maximum repetitive peak reverse voltage | | V _{RRM} | 45 | V | | |
| Maximum average forward rectified current | per device | 1 | 10 | ^ | | |
| (fig. 1) | per diode | IF(AV) | 5 | A | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | | | 100 | А | | |
| Operating junction and storage temperature range | | | -40 to +150 | °C | | |

| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|----------------------------------------------------------------------------|--------------------------------|-------------------------|-------------------------------|------|------|------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage per diode | I _F = 2.5 A | T _A = 25 °C | V _F ⁽¹⁾ | 0.44 | - | V | |
| | I _F = 5.0 A | | | 0.49 | 0.58 | | |
| | I _F = 2.5 A | T _A = 125 °C | | 0.34 | - | | |
| | I _F = 5.0 A | | | 0.41 | 0.50 | | |
| Reverse current per diode | V _B = 45 V | T _A = 25 °C | I _R ⁽²⁾ | - | 500 | μA | |
| | $v_{\rm R} = 45 v$ $T_{\rm A}$ | T _A = 125 °C | 'R (=) | 5 | 15 | mA | |

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

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VBT1045C-M3



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| THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | | |
|--------------------------------------------------------------------------------|------------|---------------------|----------|------|--|--|
| PARAMETER | | SYMBOL | VBT1045C | UNIT | | |
| Typical thermal resistance | per diode | $R_{	ext{	heta}JC}$ | 3.5 | °C/W | | |
| | per device | | 2.5 | 0/10 | | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-263AB | VBT1045C-M3/4W | 1.38 | 4W | 50/tube | Tube | | |
| TO-263AB | VBT1045C-M3/8W | 1.38 | 8W | 800/reel | Tape and reel | | |

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

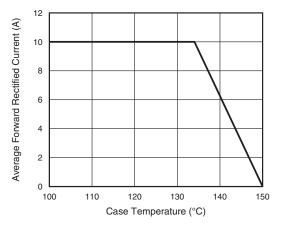


Fig. 1 - Maximum Forward Current Derating Curve

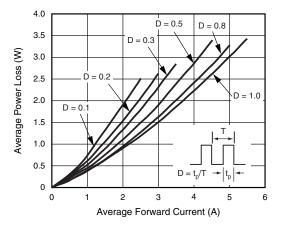
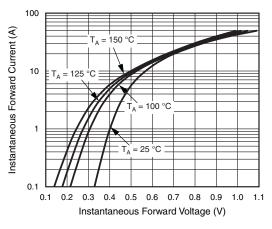


Fig. 2 - Forward Power Loss Characteristics Per Diode





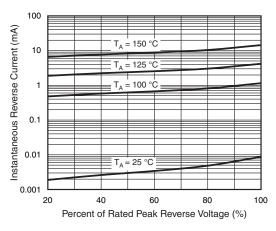
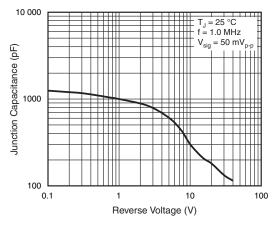


Fig. 4 - Typical Reverse Characteristics Per Diode



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Fig. 5 - Typical Junction Capacitance Per Diode

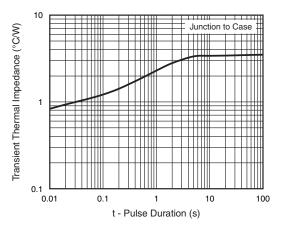
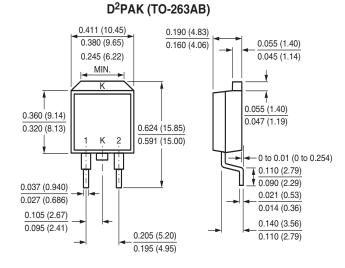
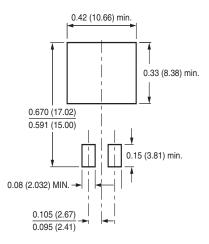


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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